



# DATA SHEET

## Hall Effect Current Sensor

PN: CHB\_SYA15D20

IPN=05~50A

### Feature

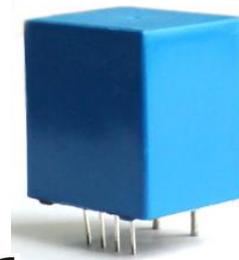
- Closed- loop (compensated) current transducer
- Capable measurement of currents: DC, AC, pulse with galvanic isolation between primary circuit and secondary circuit.
- Supply voltage: DC  $\pm 12\sim 15V$
- PCB installation

### Advantages

- High accuracy
- Easy installation
- Low temperature drift
- Optimized response time
- High immunity to external interference
- Very good linearity
- Can be customized

### Applications

- The application of variable frequency electrical appliances
- AC/DC variable-speed drive
- Uninterruptible Power Supplies (UPS)
- Switched Mode Power Supplies (SMPS)
- Inverter applications



RoHS

### Electrical data: ( $T_a=25^{\circ}C$ , $V_c=\pm 15VDC$ )

| Parmeter   | CHB05SY<br>A15D20              | CHB10SY<br>A15D20 | CHB15SY<br>A15D20 | CHB20SY<br>A15D20 | CHB30SY<br>A15D20 | CHB50SY<br>A15D20                  |
|--|--------------------------------|-------------------|-------------------|-------------------|-------------------|------------------------------------|
| Rated input $I_{pn}(A)$                          | 05                             | 10                | 15                | 20                | 30                | 50                                 |
| Measuring range $I_p(A)$                         | 0 ~ $\pm 10$                   | 0 ~ $\pm 20$      | 0 ~ $\pm 30$      | 0 ~ $\pm 40$      | 0 ~ $\pm 60$      | 0 ~ $\pm 100$                      |
| Size of Input pin *d (MM)                        | $\varnothing 0.8$              | $\varnothing 0.8$ | $\varnothing 1.0$ | $\varnothing 1.4$ | $\varnothing 1.6$ | 2 $\times$ $\square 1.6\times 1.5$ |
| Turns ratio $N_p/N_S (T)$                        | 4:1000                         | 3:1500            | 2:1500            | 1:1000            | 1:1500            | 1:2500                             |
| Inside resistance $R_M (\Omega)$                 | 50~400 $\pm 0.1\%$             |                   |                   |                   |                   |                                    |
| Output current rms $I_S(mA)$                     | $\pm 20.0*(IP/IPN)$            |                   |                   |                   |                   |                                    |
| Supply voltage $V_C(V)$                          | $(\pm 12 \sim \pm 15) \pm 5\%$ |                   |                   |                   |                   |                                    |
| Accuracy $X_G(\%)$                               | @IPN, $T=25^{\circ}C$          |                   | < $\pm 0.5$       |                   |                   |                                    |
| Offset current $IOE(mA)$                         | @IP=0, $T=25^{\circ}C$         |                   | < $\pm 0.2$       |                   |                   |                                    |
| Temperature variation of IOE $IOT(mA/^{\circ}C)$ | @IP=0, -40 ~ +85 $^{\circ}C$   |                   | < $\pm 0.005$     |                   |                   |                                    |
| Linearity error $\epsilon_r(\%FS)$               | < 0.1                          |                   |                   |                   |                   |                                    |
| Di/dt accurately followed ( $A/\mu s$ )          | > 50                           |                   |                   |                   |                   |                                    |
| Response time $t_{ra}(\mu s)$                    | @90% of IPN                    |                   | < 1.0             |                   |                   |                                    |



# Cheemi Technology Co., Ltd

|                           |                   |        |
|---------------------------|-------------------|--------|
| Power consumption IC(mA)  |                   | 15+Is  |
| Bandwidth BW(KHZ)         | @-3dB,IPN         | DC-100 |
| Insulation voltage Vd(KV) | @50/60Hz, 1min,AC | 5.0    |

## General data:

| Parameter                    | Value                  |
|------------------------------|------------------------|
| Operating temperature TA(°C) | -40 ~ +85              |
| Storage temperature TS(°C)   | -55~ +125              |
| Mass M(g)                    | 12                     |
| Plastic material             | PBT G30/G15, UL94- V0; |
| Standards                    | IEC60950-1:2001        |
|                              | EN50178:1998           |
|                              | SJ20790-2000           |

## Dimensions(mm):

| I <sub>pn</sub> <50A | I <sub>pn</sub> =50A | Connection  |
|----------------------|----------------------|---|
|                      |                      |   |
|                      |                      | General tolerance   |
|                      |                      | General tolerance: <math>\leq \pm 0.5\text{mm}</math><br>Secondary Pin size : <math>0.25 \times 0.5 \pm 0.1\text{mm}</math> |

## Remarks:

- When the current goes through the primary pin of a sensor, the voltage will be measured at the output end.
- Custom design is available for the different rated input current and the output voltage.
- The dynamic performance is the best when the primary hole is fully filled with.
- The primary conductor should be <math>< 100^\circ\text{C}</math>.

**WARNING : Incorrect wiring may cause damage to the sensor.**

